

Preliminary

Dual Power MOSFET Module

$$V_{DSS} = 70 \text{ V}$$

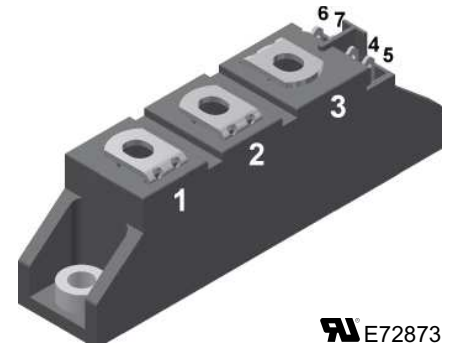

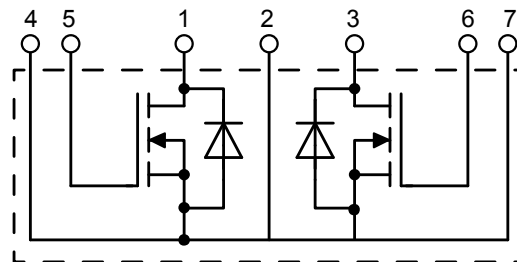
$$I_{D25} = 165 \text{ A}$$

$$R_{DS(on)} = 7 \text{ m}\Omega$$

Common-Source connected
N-Channel Enhancement Mode

Part number

VMK165-007T


 E72873


Features / Advantages:

- Two MOSFET with common source
- Direct copper bonded Al₂O₃ ceramic base plate
- Low R_{DS(on)} HDMOS™ process
- Low package inductance for high speed switching
- Kelvin source contact
- Keyed twin plugs
- High power density
- Low losses

Applications:

- Push-pull inverters
- Switched-mode and resonant-mode power supplies
- Uninterruptible power supplies (UPS)
- AC static switches

Package: TO-240AA

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

Disclaimer Notice

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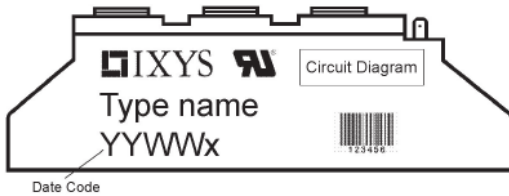
| MOSFETs | | | | Ratings | | | |
|--------------|---|---|------|---------|----------|---------------------|--|
| Symbol | Definitions | Conditions | min. | typ. | max. | Unit | |
| V_{DSS} | drain source breakdown voltage | $T_{VJ} = 25^{\circ}\text{C to } 125^{\circ}\text{C}$ | | | 70 | V | |
| V_{DGR} | drain gate voltage | $R_{GS} = 6.8 \text{ k}\Omega$ $T_{VJ} = 25^{\circ}\text{C to } 125^{\circ}\text{C}$ | | | 70 | V | |
| V_{GS} | gate source voltage | Continuous | | | ± 20 | V | |
| V_{GSM} | max. transient gate source voltage | Transient | | | ± 30 | V | |
| I_{D25} | continuous drain current | $T_C = 25^{\circ}\text{C}$ | | | 165 | A | |
| I_{D100} | drain current | $T_C = 100^{\circ}\text{C}$ | | | 104 | A | |
| I_{DM} | maximum pulsed drain current | $t_p = 10 \mu\text{s}$, pulse width limited by T_{JM} $T_C = 25^{\circ}\text{C}$ | | | 660 | A | |
| P_{tot} | total power dissipation | $T_{VJ} = 125^{\circ}\text{C}$ $T_C = 25^{\circ}\text{C}$ | | | 390 | W | |
| V_{DSS} | drain source breakdown voltage | $V_{GS} = 0 \text{ V}; I_D = 1 \text{ mA}$ | 70 | | | V | |
| $V_{GS(th)}$ | gate threshold voltage | $V_{DS} = V_{GS}; I_D = 8 \text{ mA}$ | 2 | | 4 | V | |
| I_{GSS} | gate source leakage current | $V_{GS} = \pm 20 \text{ V DC}; V_{DS} = 0$ | | | 500 | nA | |
| I_{DSS} | drain source leakage current | $V_{DS} = V_{DSS}; V_{GS} = 0 \text{ V}$ $V_{DS} = 0.8 \cdot V_{DSS}; V_{GS} = 0 \text{ V}$ $T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$ | | | 200 1 | μA mA | |
| $R_{DS(on)}$ | static drain source on resistance | $V_{GS} = 10 \text{ V}; I_D = 0.5 \cdot I_{D25}$ Pulse test, $t \leq 300 \mu\text{s}$, duty cycle $d \leq 2 \%$ $T_{VJ} = 25^{\circ}\text{C}$ | | 6 | 7 | m Ω | |
| g_{fs} | forward transconductance | $V_{DS} = 10 \text{ V}; I_D = 0.5 \cdot I_{D25}$ pulsed | 60 | 80 | | S | |
| C_{iss} | input capacitance | $V_{GS} = 0 \text{ V}; V_{DS} = 25 \text{ V}; f = 1 \text{ MHz}$ | | 8.8 | | nF | |
| C_{oss} | output capacitance | | | 4.0 | | nF | |
| C_{rss} | reverse transfer (Miller) capacitance | | | 2.4 | | nF | |
| $t_{d(on)}$ | turn-on delay time | $V_{GS} = 10 \text{ V}; V_{DS} = 0.5 \cdot V_{DSS}; I_D = 0.5 \cdot I_{D25}$ $R_G = 1 \Omega$ (external), resistive load | | 120 | | ns | |
| t_r | current rise time | | | 280 | | ns | |
| $t_{d(off)}$ | turn-off delay time | | | 390 | | ns | |
| t_f | current fall time | | | 110 | | ns | |
| Q_g | total gate charge | $V_{GS} = 10 \text{ V}; V_{DS} = 0.5 \cdot V_{DSS}; I_D = 0.5 \cdot I_{D25}$ | | 480 | | nC | |
| Q_{gs} | gate source charge | | | 60 | | nC | |
| Q_{gd} | gate drain (Miller) charge | | | 240 | | nC | |
| R_{thJC} | thermal resistance junction to case | with heat transfer paste | | | 0.32 | K/W | |
| R_{thJH} | thermal resistance junction to heatsink | | | 0.2 | | K/W | |

| Source-Drain Diodes | | | | Ratings | | | |
|---------------------|-------------------------------|---|------|---------|------|------|--|
| Symbol | Definitions | Conditions | min. | typ. | max. | Unit | |
| I_S | continuous source current | $V_{GS} = 0 \text{ V}$ | | | 165 | A | |
| I_{SM} | maximum pulsed source current | Repetitive; pulse width limited by T_{JM} | | | 660 | A | |
| V_{SD} | forward voltage drop | $I_F = I_S; V_{GS} = 0 \text{ V}$ Pulse test, $t \leq 300 \mu\text{s}$, duty cycle $d \leq 2 \%$ | | | 1.5 | V | |
| t_{rr} | reverse recovery time | $I_F = 50 \text{ A}$, $-di/dt = 200 \text{ A}/\mu\text{s}$; $V_{DS} = 25 \text{ V}; V_{GS} = 0 \text{ V}$ | | 150 | | ns | |

Data according to IEC 60747 and refer to a single thyristor/diode unless otherwise stated. $T_J = 25^{\circ}\text{C}$, unless otherwise specified

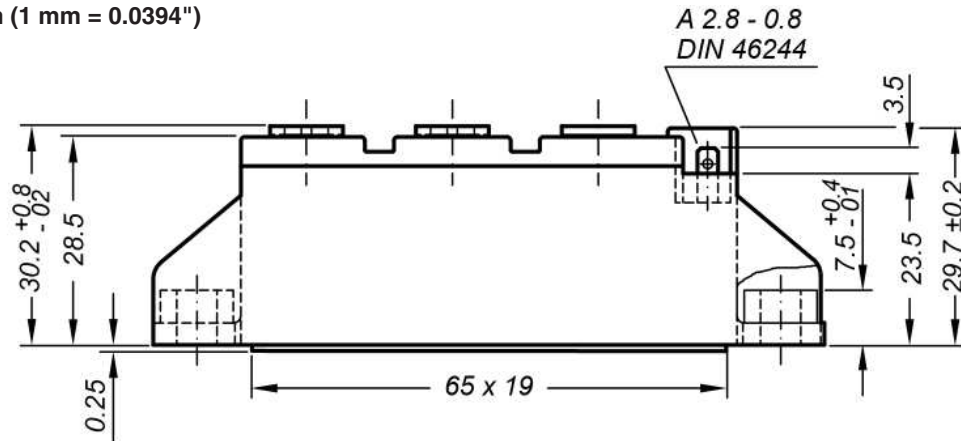


| Package TO-240AA | | Ratings | | | | |
|------------------|--|----------------------|------|-------------------------------------|------|------|
| Symbol | Definitions | Conditions | min. | typ. | max. | Unit |
| I_{RMS} | RMS current | per terminal | | | 200 | A |
| T_{VJ} | virtual junction temperature | | -40 | | 150 | °C |
| T_{VJM} | maximum virtual junction temperature | | | | 150 | °C |
| T_{stg} | storage temperature | | -40 | | 125 | °C |
| Weight | | | | 81 | | g |
| M_D | mounting torque | | 2.5 | | 4 | Nm |
| M_T | terminal torque | | 2.5 | | 4 | Nm |
| $d_{Spp/App}$ | creepage distance on surface / striking distance through air | terminal to terminal | 13.0 | 9.7 | | mm |
| $d_{Spb/Appb}$ | | terminal to backside | 16.0 | 16.0 | | mm |
| V_{ISOL} | isolation voltage | t = 1 second | | | 4800 | V |
| | | t = 1 minute | | 50/60 Hz, RMS, $I_{ISOL} \leq 1$ mA | 4000 | V |

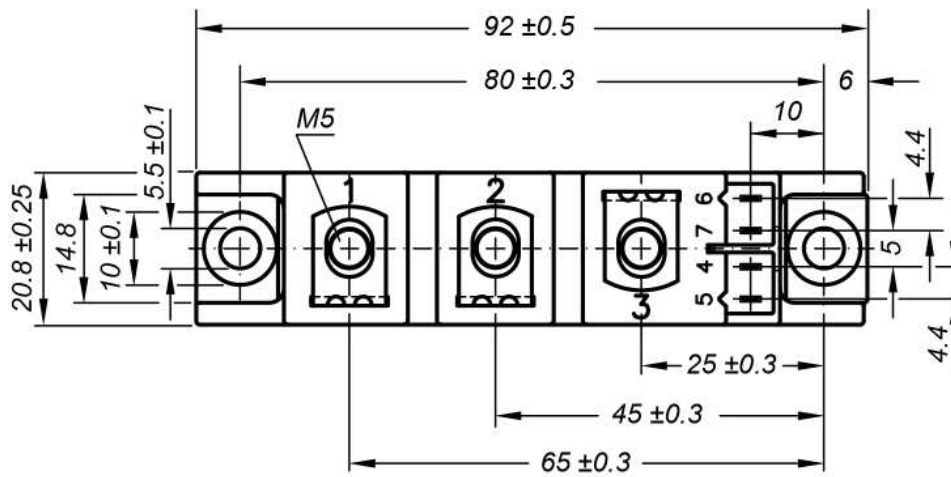


Outlines TO-240AA

Dimensions in mm (1 mm = 0.0394")



General tolerance: DIN ISO 2768 class „c“



Optional accessories for modules

Keyed gate/cathode twin plugs with wire length = 350 mm, gate = white, cathode = red

Type ZY 200L (L = Left for pin pair 4/5)

Type ZY 200R (R = Right for pin pair 6/7) } UL 758, style 3751

